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OLP Note: Q.1 is compulse

PHZ018 05/04/18

App Physics I Q. P. Code: 39777

Time: 2 hours Marks: 60

Note: Q.1 is compulsory

Attempt any three from Q.2 to Q.6

Assume suitable data if necessary, (Avogadro's No= 6.02X10<sup>26</sup> per kg mole)

| Q.1                | Attempt any five  | Marks    |
|--------------------|---|----------|
| a                  | Identify crystal structure if its density is 9.6 X 10 <sup>2</sup> kg/m <sup>3</sup> and lattice constant is 4.3 Angstrom. (atomic weight 23)   | 3        |
| b                  | Explain the concept of hole? In Intrinsic semiconductor if number of electrons in conduction band is "x" find the number of holes in valence band   | 3        |
| С                  | Write the advantages of solar cell  | 3<br>3   |
| d                  | What is meant by active and passive dielectrics?  | 3        |
| e                  | Define the terms permeability, relative permeability and susceptibility with reference to magnetic materials.   | <b>3</b> |
| $\mathbf{f}$       | Explain Frankle defect in crystal imperfections.  | 3        |
| g                  | In Piezo electric Oscillator what is the role of resonance?   | 3        |
| Q.2                |   | _        |
| a<br>b             | Draw the unit cell of HCP. Derive (i) atoms/ unit cell (ii) atomic radius (iii) APF Explain the term "Ligancy" why certain ligancies are not possible? Calculate critical radius                          | 8<br>7   |
| Ü                  | ratio for Ligancy 3.  |          |
| 0.3                |   |          |
| Q.3<br>a           | What is the term "Hysteresis"? Draw Hysteresis loop explain various important point on  | 8        |
|                    | it. What is the technical significance of area enclosed under it? For a transformer which   |          |
| b                  | kind of material will you prefer the one with small Hysteresis loop area or the big one? Silicon has the same crystal structure as of diamond. Its density is 2.33X 10 <sup>3</sup> kg/m <sup>3</sup> and | 7        |
|                    | atomic weight 28.9. Calculate atomic radius and lattice constant  |          |
| Q.4                |   |          |
| a                  | Draw the following [120], (100), (001), [121], [210]  | 5        |
| b                  | What is Fermi level? Draw suitable diagrams to show its position in intrinsic semiconductor, p and n type semiconductor. Also draw its variation with temperature in p                                    | 5        |
|                    | type  |          |
| C                  | Describe various polarization mechanisms in dielectrics.  | 5        |
| Q.5                |   |          |
| a े                | State and derive Bragg's Law  | 5<br>5   |
| b                  | Describe the Hall effect experiment to find the type of extrinsic semiconductor with proper labelled diagram  | , 3      |
| e .                | A hall of dimension 20 x 15x 10 m <sup>3</sup> has average absorption coefficient 0.1. Find the   | 5        |
|                    | reverberation time. If a curtain cloth of 100m <sup>2</sup> is suspended at the centre of the hall with absorption coefficient 0.66, find the change in reverberation time                                |          |
|                    |   |          |
| Q:6                | The District Colon 2 It will be a second to Waite at least 2 points as comparison with alcotric   | 5        |
| S` <b>a</b><br>S S | Explain Ohm's law for magnetic circuit. Write at least 2 points as comparison with electric circuit   | 3        |
| b ·                | What is Cavitation? Write its applications( any three)  | 5        |
| C.                 | The Hall coefficient for a specimen is given as $3.66 \times 10^{-4} \text{ m}^3 / \text{C}$ . Its resistively is $8.93 \times 10^{-3} \Omega$ m. Find its $\mu$ and n.                                   | 5        |
| A 15 4             | ·   |          |